

### »Features

- 280Watts peak pulse power ( $t_p = 8/20\mu s$ )
- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Protection one data/power line
- IEC 61000-4-2  $\pm 8kV$  contact  $\pm 15kV$  air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 5A (8/20 $\mu s$ )



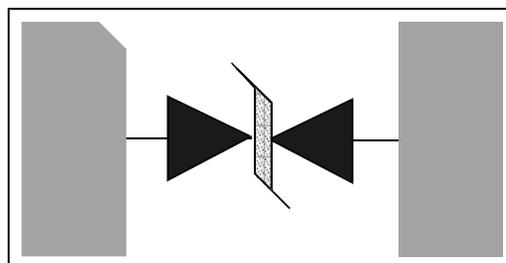
### »Applications

- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

### »Mechanical Data

- DFN1006 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

### »Schematic & PIN Configuration



**DFN1006**

### »Absolute Maximum Rating

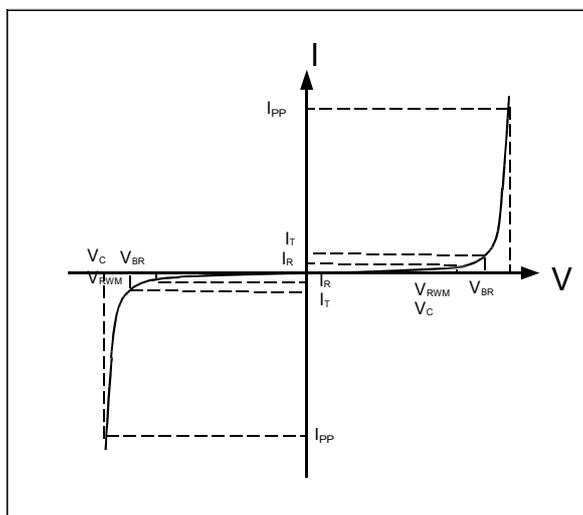
Rating	Symbol	Value	Units
Peak Pulse Power ( $t_p = 8/20\mu s$ )	$P_{PP}$	280	Watts
Peak Pulse Current ( $t_p = 8/20\mu s$ )(note1)	$I_{pp}$	5	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	$V_{ESD}$	15 8	kV
Lead Soldering Temperature	$T_L$	260(10seconds)	°C
Junction Temperature	$T_J$	-55 to + 125	°C
Storage Temperature	$T_{stg}$	-55 to + 125	°C

### »Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	$V_{RWM}$				24	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T = 1mA$	26.7			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 24V, T = 25^\circ C$		0.1	0.5	$\mu A$
Peak Pulse Current	$I_{pp}$	$t_p = 8/20\mu s$			5	A
Clamping Voltage	$V_C$	$I_{pp} = 5A, t_p = 8/20\mu s$		44		V
Junction Capacitance	$C_j$	$V_R = 0V, f = 1MHz$		20	25	pF

### »Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current



Note: 8/20 $\mu s$  pulse waveform.

»Typical Characteristic

Fig.1 Peak Pulse Power Rating Curve

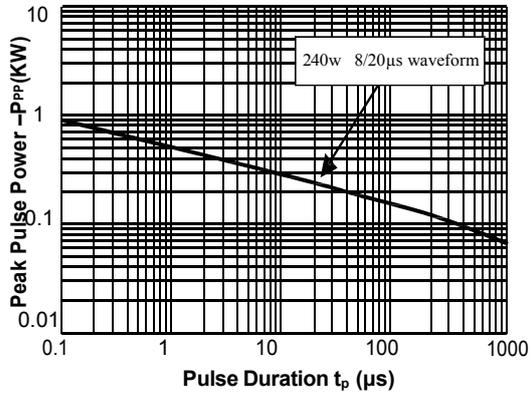


Fig.2 Pulse Derating Curve

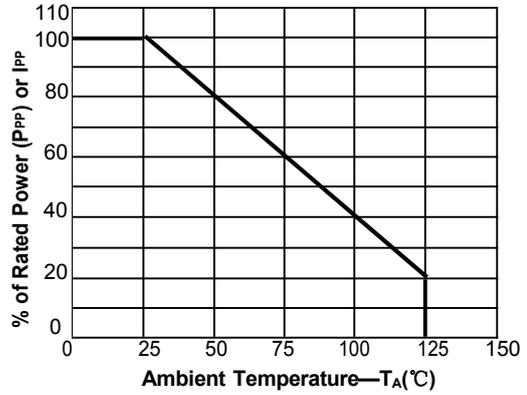


Fig.3 PulseWaveform-8/20μs

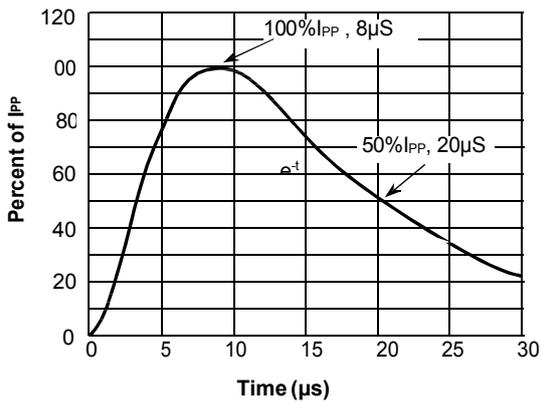


Fig.4 PulseWaveform-ESD(IEC61000-4-2)

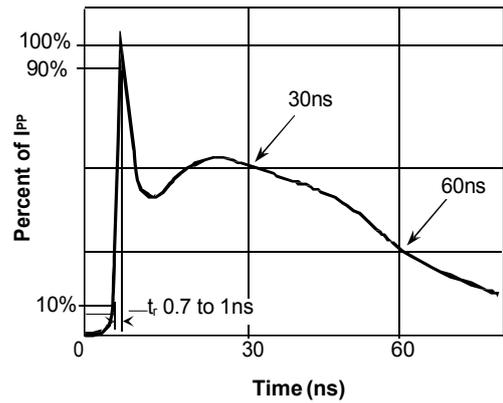


Fig.5 IEC61000-4-2 +8kV ContactDischarge

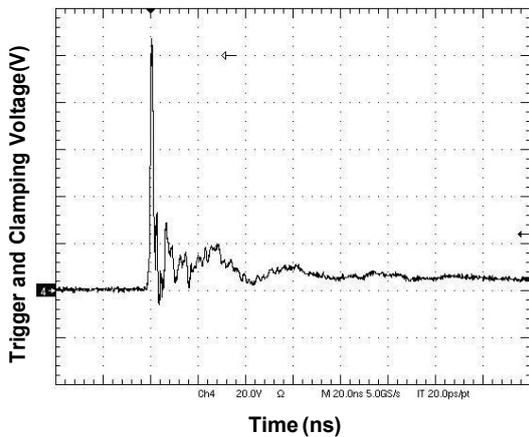
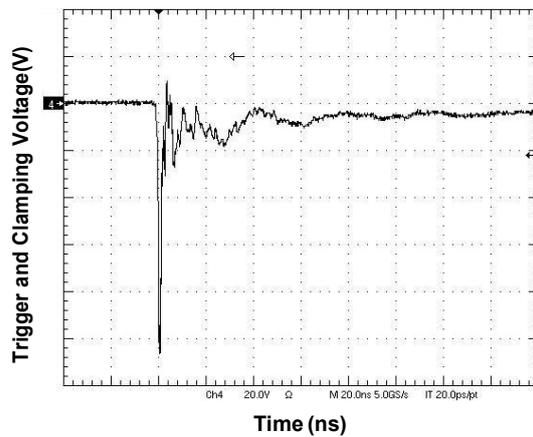
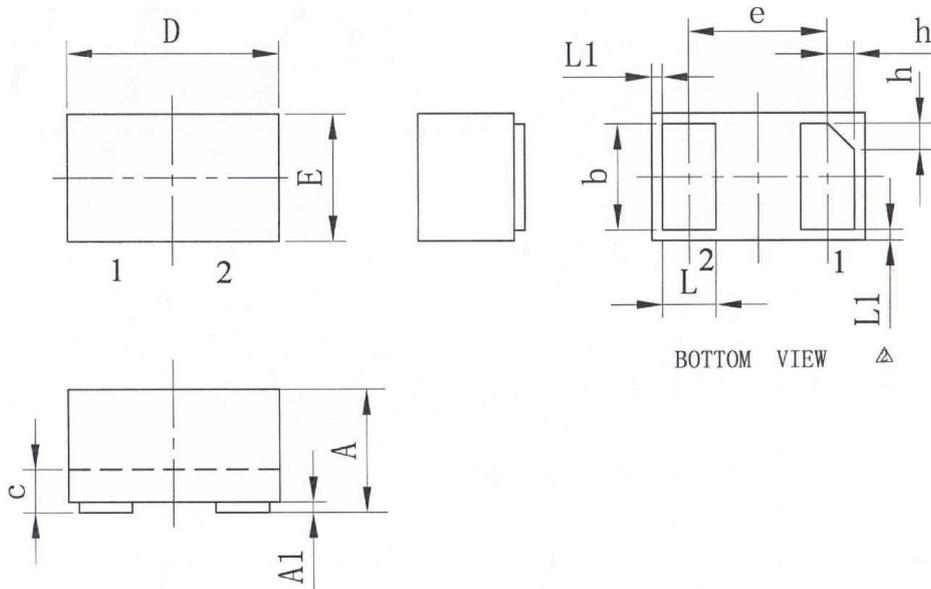


Fig.6 IEC61000-4-2 -8kV ContactDischarge

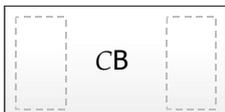


»Outline Drawing – DFN1006



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.45	0.50	0.55
A1	0	0.02	0.05
b	0.45	0.50	0.55
c	0.12	0.15	0.18
D	0.95	1.00	1.05
e	0.65BSC		
E	0.55	0.60	0.65
L	0.20	0.25	0.30
L1	0.05REF		
h	0.07	0.12	0.17
载体尺寸 (M1)	20*20		

»Marking



»Ordering information

Order code	Package	Base qty	Delivery mode
BCSPHV24	DFN1006	10k	Tape and reel

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